



Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
30V	25mΩ @ V _{GS} = 10V	6.2A
	28mΩ @ V _{GS} = 4.5V	5.8A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Load Switch
- DC-DC Converters
- Power Management Functions

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

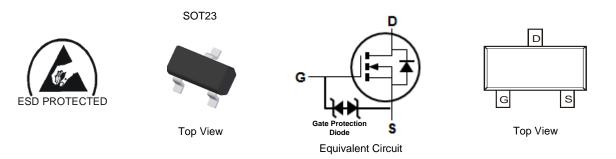
N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3028LQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3028LQ-7	SOT23	3,000/Tape & Reel
DMN3028LQ-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

_		
	4N7	ΥM

4N7 = Product Type Marking Code $Y or <math>\overline{Y} = Year (ex: H = 2020)$ M = Month (ex: 9 = September)

Date Code Key												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6) Vcs = 10V		T _A = +25°C T _A = +70°C	ID	6.2 4.9	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1	Ідм	40	A		
Maximum Body Diode Forward Current (Note 6)	ls	2	A		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.86	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	146	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		Reja	88	°C/W
Thermal Resistance, Junction to Case (Note 6)		Rejc	13	C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.8	—	1.8	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	Rds(on)		16 19 47	25 28 68	mΩ	V _{GS} = 10V, I _D = 4.0A V _{GS} = 4.5V, I _D = 3.5A V _{GS} = 2.5V, I _D = 2.5A
Source-Drain Diode Forward Voltage	Vsd		0.7	1.2	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	680	_	pF	
Output Capacitance	Coss	_	96	—	pF	Vps = 15V, Vgs = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	74	—	pF	
Gate Resistance	Rg	_	1.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	10.9	—	nC	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	7.8	—	nC	V _{DS} = 15V, I _D = 4A
Gate-Source Charge	Qgs		1.6	—	nC	VDS = 15V, ID = 4A
Gate-Drain Charge	Q _{gd}		4.8	_	nC	
Turn-On Delay Time	td(on)		6.7	—	ns	
Turn-On Rise Time	t _R		1.5	—	ns	$V_{DD} = 15V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)		17.5	—	ns	$R_L = 15\Omega, R_G = 6\Omega$
Turn-Off Fall Time	t _F	-	10.4	_	ns	

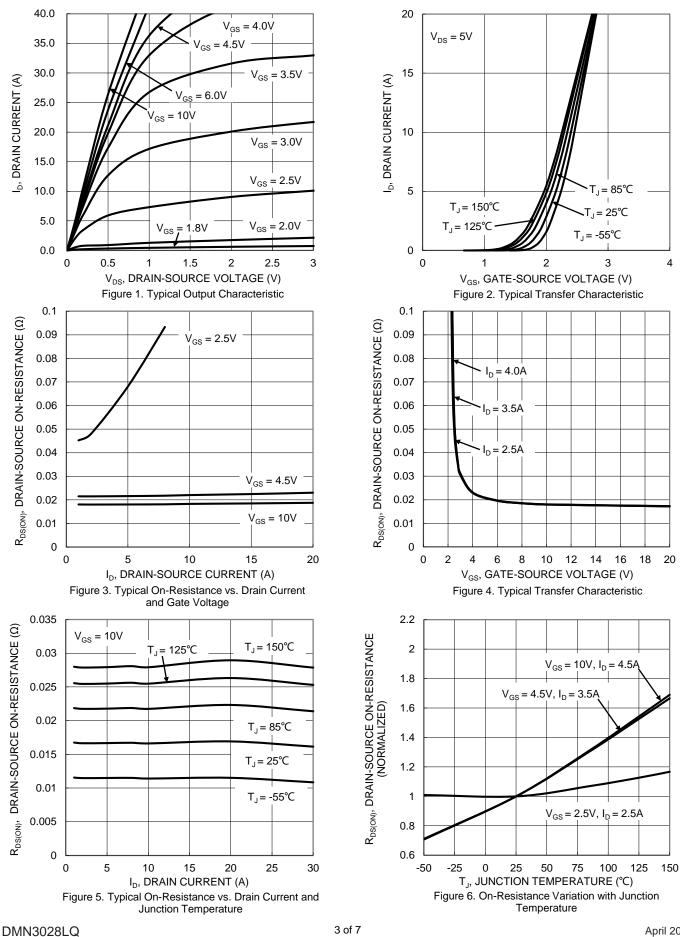
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

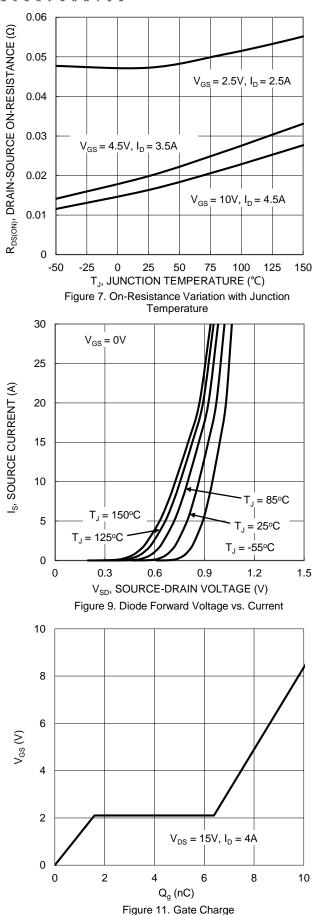


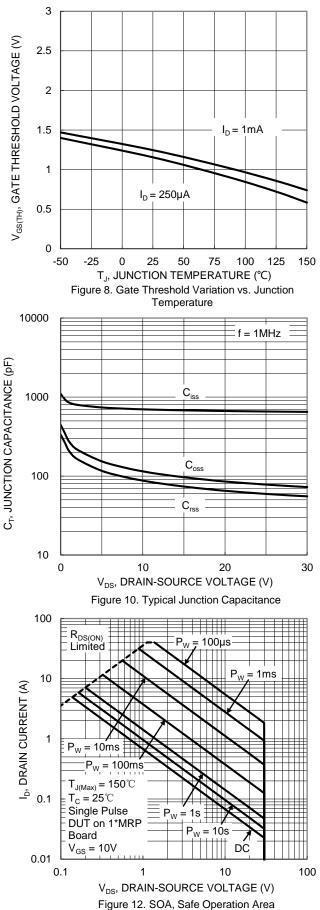
DMN3028LQ



Document number: DS42375 Rev. 2 - 2



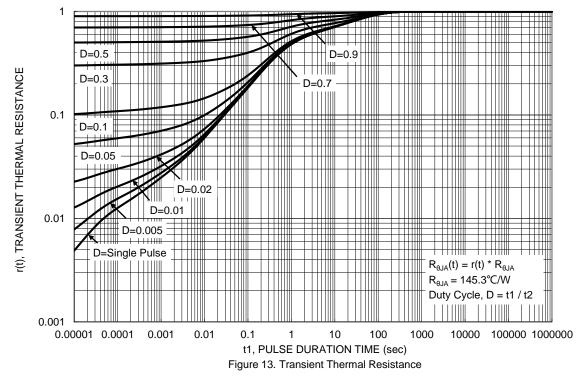




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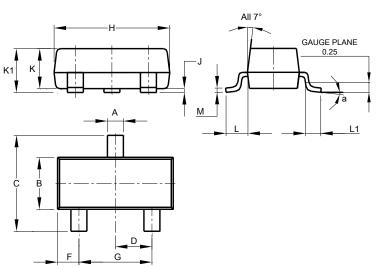






Package Outline Dimensions

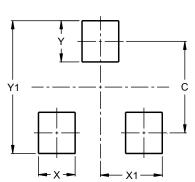
Please see http://www.diodes.com/package-outlines.html for the latest version.



l –	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
ĸ	0.890	1.00	0.975					
K1	0.903 1.10 1.0		1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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